

## UNITED STATES PATENT AND TRADEMARK OFFICE



UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	F.	ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/645,646	08/22/2003		Guy Moshe Cohen	YOR920030328US1	8783
21254	7590	08/08/2005		EXAMINER	
MCGINN	•		BLUM, DAVID S		
SUITE 200	JOURTH	OUSE ROAD		ART UNIT	PAPER NUMBER
VIENNA, V	VA 22182	2-3817	2813		
				DATE MAILED: 08/08/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(a)				
	Application No.	Applicant(s)				
Office Action Summary	10/645,646	COHEN, GUY MOSHE				
Office Action Summary	Examiner	Art Unit				
	David S. Blum	2813				
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence address				
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period w  - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	86(a). In no event, however, may a reply be ting within the statutory minimum of thirty (30) day rill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 20 Ap	oril 2005.					
2a) This action is <b>FINAL</b> . 2b) ☑ This	action is non-final.	•				
	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims						
4) ⊠ Claim(s) 1-27 is/are pending in the application. 4a) Of the above claim(s) 13-20 and 25-27 is/are withdrawn from consideration.  5) □ Claim(s) is/are allowed.  6) ☒ Claim(s) 1-12 and 21-24 is/are rejected.  7) □ Claim(s) is/are objected to.  8) ☒ Claim(s) 1-27 are subject to restriction and/or election requirement.						
Application Papers						
9) The specification is objected to by the Examine	r.					
10)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.						
Applicant may not request that any objection to the	drawing(s) be held in abeyance. See	e 37 CFR 1.85(a).				
Replacement drawing sheet(s) including the correcting.  11) The oath or declaration is objected to by the Ex	· · · · · · · · · · · · · · · · · ·	•				
Priority under 35 U.S.C. § 119						
<ul> <li>12) Acknowledgment is made of a claim for foreign</li> <li>a) All b) Some * c) None of:</li> <li>1. Certified copies of the priority documents</li> <li>2. Certified copies of the priority documents</li> <li>3. Copies of the certified copies of the priority application from the International Bureau</li> <li>* See the attached detailed Office action for a list of the certified copies</li> </ul>	s have been received. s have been received in Applicati ity documents have been receive (PCT Rule 17.2(a)).	on No ed in this National Stage				
Attachment(s)						
1) Notice of References Cited (PTO-892)	4) Interview Summary					
<ul> <li>2) Notice of Draftsperson's Patent Drawing Review (PTO-948)</li> <li>3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)</li> </ul>	Paper No(s)/Mail Da 5) Notice of Informal P	ate Patent Application (PTO-152)				
Paper No(s)/Mail Date 11/10/03.	6) Other:					

Application/Control Number: 10/645,646 Page 2

Art Unit: 2813

This action is in response to the election filed 4/20/05.

## **DETAILED ACTION**

## Election/Restrictions

- 1. Applicant's election without traverse of claims 1-12 and 21-24 in the reply filed on 4/20/05 is acknowledged.
- 2. Claims 13-20 and 25-27 are withdrawn from further consideration pursuant to 37 CFR 1.142(b) as being drawn to a nonelected invention, there being no allowable generic or linking claim. Election was made **without** traverse in the reply filed on 4/20/05.

## Claim Rejections - 35 USC § 102

3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 4. Claims 1-12 and 21-24 are rejected under 35 U.S.C. 102(e) as being anticipated by Joshi (US006921982B2).

Joshi teaches the device of claims 1-12 and 21-24 as follows.

Art Unit: 2813

Regarding claim 1, Joshi teaches a channel of strained silicon germanium adjacent a source and drain (12 and 14), column 10 lines 9-10), two gates (88 and 89), the gates on a dielectric layer (see column 6 lines 13-18, gate on dielectric), and the channel is non-planar (figure 8F).

Regarding claim 2, the channel thickness is relatively uniform (figure 8F).

Regarding claim 3, the channel material may be epitaxially grown (column 8 lines 1-4).

Regarding claim 4, Joshi forms high quality SiGe free from dislocations (column 7 lines 18-20). The examiner considers this to mean "defect free".

Regarding claim 5, the strained-silicon channel includes a distorted lattice cell. This is inherent to a strained layer.

Regarding claim 6, the gates are independently controlled (column 10 line 12).

Regarding claim 7, the strained silicon channel comprises a fin (figure 8F and column 10 line 4).

Application/Control Number: 10/645,646

Art Unit: 2813

Regarding claim 8, the first and second gates are self-aligned (islands are precision aligned (column 7 lines 39-40), thus resulting gates would be self aligned.).

Regarding claim 9, the limitation of forming the first and second gates in a single lithography step is a process limitation (product by process) and has no patentable weight in device claims.

Even though product-by-process claims are limited by and defined by the process, determination of Patentability is based upon the product itself. The patentability of a product does not depend on its method of production." MPEP 2113

Regarding claim 10, the first and second gates are self-aligned as above (see claim 8) and also aligned with the source and drain, thus all are self-aligned.

Regarding claim 11, the background of the invention teaches that it is known to use one or more fins (column 1 line 42-44). Also see column 7 lines 64-65 and column 8 lines. 42-43).

Regarding claim 12, the device includes a planarized top (figure 8F).

Regarding claim 21, Joshi teaches a channel of strained silicon germanium adjacent a source and drain (12 and 14), column 10 lines 9-10), two gates (88 and 89), the gates on a dielectric layer (see column 6 lines 13-18, gate on dielectric), and the channel is

Art Unit: 2813

non-planar (figure 8F), the strained silicon channel comprises a fin (figure 8F and column 10 line 4).

Regarding claim 22, a circuit may comprise the device of claim 1 (column 1 lines 14-45).

Regarding claim 23, the strained silicon channel is compressively strained (column 5 line 45).

Regarding claim 24, the strained silicon channel is compressively strained (column 5 line 45 and column 6 line 66).

5. Any inquiry concerning this communication or earlier communications from the examiner should be directed to David S. Blum whose telephone number is (571)-272-1687) and e-mail address is <a href="mailto:David.blum@USPTO.gov">David.blum@USPTO.gov</a>.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl Whitehead Jr., can be reached at (571)-272-1702. Our facsimile number all patent correspondence to be entered into an application is (571) 273-8300.

Application/Control Number: 10/645,646

Art Unit: 2813

Page 6

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

David S. Blum

August 4, 2005